

SPECIFICATION

- Supplier : Samsung electro-mechanics
- Product : Multi-layer Ceramic Capacitor
- Samsung P/N : **CL21B225KAFNNNE**
- Description : **CAP, 2.2 μ F, 25V, \pm 10%, X7R, 0805**

A. Samsung Part Number

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| ① Series | Samsung Multi-layer Ceramic Capacitor | | | | | | | | | |
| ② Size | 0805 (inch code) | L: 2.0 \pm 0.1 mm | W: 1.25 \pm 0.1 mm | | | | | | | |
| ③ Dielectric | X7R | ⑧ Inner electrode | | Ni | | | | | | |
| ④ Capacitance | 2.2 μ F | Termination | | Cu | | | | | | |
| ⑤ Capacitance tolerance | \pm 10 % | Plating | | Sn 100% (Pb Free) | | | | | | |
| ⑥ Rated Voltage | 25 V | ⑨ Product | | Normal | | | | | | |
| ⑦ Thickness | 1.25 \pm 0.1 mm | ⑩ Special | | Reserved for future use | | | | | | |
| | | ⑪ Packaging | | Embossed Type, 7" reel | | | | | | |

B. Samsung Reliability Test and Judgement condition

| | Performance | Test condition |
|----------------------------------|---|--|
| Capacitance | Within specified tolerance | 1kHz \pm 10% 1.0 \pm 0.2Vrms |
| Tan δ (DF) | 0.1 max. | |
| Insulation Resistance | 10,000Mohm or 100Mohm $\cdot\mu$ F Whichever is Smaller | Rated Voltage 60~120 sec. |
| Appearance | No abnormal exterior appearance | Microscope (\times 10) |
| Withstanding Voltage | No dielectric breakdown or mechanical breakdown | 250% of the rated voltage |
| Temperature Characterisitcs | X7R (From -55 $^{\circ}$ C to 125 $^{\circ}$ C, Capacitance change should be within \pm 15%) | |
| Adhesive Strength of Termination | No peeling shall be occur on the terminal electrode | 500g-F, for 10 \pm 1 sec. |
| Bending Strength | Capacitance change : within \pm 12.5% | Bending to the limit (1mm) with 1.0mm/sec. |
| Solderability | More than 75% of terminal surface is to be soldered newly | SnAg3.0Cu0.5 solder 245 \pm 5 $^{\circ}$ C, 3 \pm 0.3sec. (preheating : 80~120 $^{\circ}$ C for 10~30sec.) |
| Resistance to Soldering heat | Capacitance change : within \pm 7.5% Tan δ , IR : initial spec. | Solder pot : 270 \pm 5 $^{\circ}$ C, 10 \pm 1sec. |

| | Performance | Test condition |
|------------------------------------|---|---|
| Vibration Test | Capacitance change : within $\pm 5\%$ Tan δ , IR : initial spec. | Amplitude : 1.5mm From 10Hz to 55Hz (return : 1min.) 2hours \times 3 direction (x, y, z) |
| Moisture Resistance | Capacitance change : within $\pm 12.5\%$ Tan δ : 0.125 max IR : 12.5M $\Omega \cdot \mu F$ or Over | With rated voltage 40 $\pm 2^\circ C$, 90~95%RH, 500+12/-0hrs |
| High Temperature Resistance | Capacitance change : within $\pm 12.5\%$ Tan δ : 0.125 max IR : 25M $\Omega \cdot \mu F$ or Over | With 150% of the rated voltage Max. operating temperature 1000+48/-0hrs |
| Temperature Cycling | Capacitance change : within $\pm 7.5\%$ Tan δ , IR : initial spec. | 1 cycle condition Min. operating temperature $\rightarrow 25^\circ C$ \rightarrow Max. operating temperature $\rightarrow 25^\circ C$ 5 cycle test |

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^\circ C$, 10sec. Max)

* For the more detail Specification, Please refer to the Samsung MLCC catalogue.